**Influence of illumination spectrum on dissociation kinetic of iron-boron pairs in silicon**

Oleg Olikh, Oleksandr Datsenko, Serhiy Kondratenko

*Taras Shevchenko National University of Kyiv, 64/13, Volodymyrska Street, Kyiv, 01601, Ukraine*

olegolikh@knu.ua

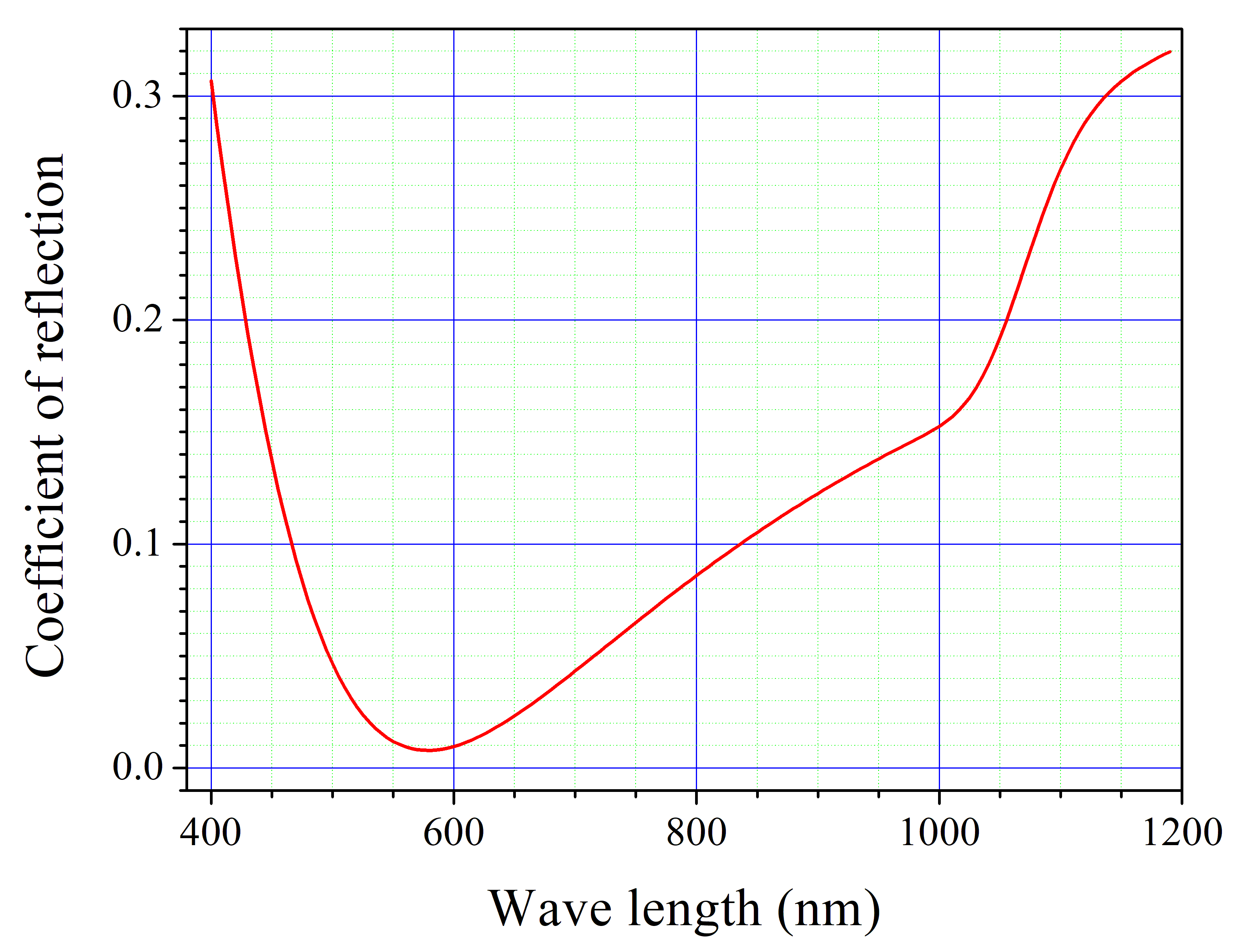


Fig.S1. The spectral dependence of the coefficient of reflectance for silicon solar cell with antireflective and passivating SiO2 (30 nm) and Si3N4 (40 nm) layers on the front surface. The calculations take into account multiple reflections.